

PRINTER RUSH
(PTO ASSISTANCE)

Application : 10/810631 Examiner : Tran GAU : 2818
From : J. Black Location : (IDC) FMF FDC Date : 4/22/05
Tracking # : 06072223 Week Date : 1/31/05

DOC CODE	DOC DATE	MISCELLANEOUS
<input checked="" type="checkbox"/> 1449	<u>9/21/04</u>	<input type="checkbox"/> Continuing Data
<input type="checkbox"/> IDS		<input type="checkbox"/> Foreign Priority
<input type="checkbox"/> CLM		<input type="checkbox"/> Document Legibility
<input type="checkbox"/> IIFW		<input type="checkbox"/> Fees
<input type="checkbox"/> SRFW		<input type="checkbox"/> Other
<input type="checkbox"/> DRW		
<input type="checkbox"/> OATH		
<input type="checkbox"/> 312		
<input type="checkbox"/> SPEC		

[RUSH] MESSAGE:

Sheet 1 of 5: First other document has data cut-off on
right side of page.

Please resolve.

[XRUSH] RESPONSE:

Corrected

Carl Brendidge

703-684-1120

INITIALS: PS

NOTE: This form will be included as part of the official USPTO record, with the Response document coded as XRUSH.

REV 10/04

4/29



501.35478 CX22

10/8/03

SHEET 1 OF 5

FORM PTO-1449 U.S. Department of Commerce Patent and Trademark Office	ATTY. DOCKET NO.	SERIAL NO.
	501.35478CX22	Not yet assigned
	APPLICANT MIWA, et al	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)	FILING DATE	GROUP
	March 29, 2004	2818

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	4 9 6 4 0 7 9	10/90	Devlin			
	5 3 6 5 4 8 6	11/94	Schreck			
	5 4 1 2 6 0 1	5/95	Sawada et al	365	185.03	
	5 8 3 1 9 0 0	11/98	Miyamoto	365	185.03	
	5 7 4 5 4 0 9	4/98	Wong et al	365	185.03	
	5 5 5 5 2 0 4	9/96	Endoh et al	365	189.01	
	5 1 5 1 3 8 7	9/92	Brady et al	437	191	4/30/90
	5 0 8 4 4 1 7	1/92	Joshi et al	437	192	3/13/89
	5 0 5 9 5 5 4	10/91	Spinner et al	437	193	6/23/89
	5 1 7 2 3 3 8	12/92	Mehrotra et al			
	5 1 3 8 5 7 6	8/92	Madurawe			
	5 4 8 7 0 3 8	1/96	Akaogi et al	365	185.23	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	ABSTRACT	
						YES	NO
5	9 1 2 1 6 9 6	7/84	Japan			XX	
	4 2 3 8 1 9 6	8/92	Japan				XX
	4 5 7 2 9 4	2/92	Japan				XX

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Digest of Technical Papers, ATP 2.1: A 3.3V 128Mb Multi-level NAND Flash Memory for Mass Storage Applications, T. Jung, et al., ISSCC96/Session 2/Flash Memory/Paper TP 2.1, 1996 IEEE International Solid State Circuits Conf.
	Betty Prince, "Semiconductor Memories", 1983, Wisely, 2 nd Edition, pp. 620-621.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation is considered, draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

(Form PTO-1449 [6-4])